

NC20

BANK CAPACITOR PROTECTION RELAY
THE COMPREHENSIVE SOLUTION
FOR CAPACITOR BANK PROTECTION



— Application

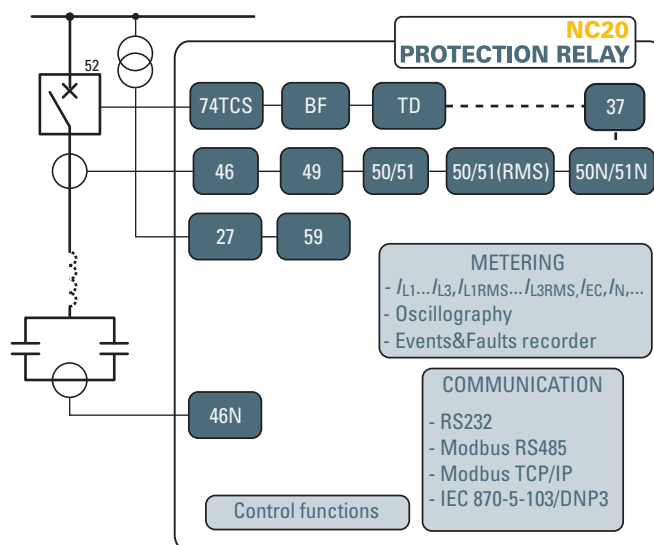
The relay type NC20 provides protection of shunt capacitor banks and harmonic filter circuits.

- The capacitor banks may have the following configurations:
- Single Wye grounded.
- Single Wye ungrounded (with a resistor on the output of the neutral unbalance voltage transformer in order to develop the appropriate input current for the unbalance protection).
- Double Wye ungrounded.

The capacitor banks may be: internally/externally fused or fuseless capacitor units.

A suitable compensation method is provided to compensate the inherent unbalance neutral current

Protection 37, 49 and 50/51 (RMS) are based on RMS value measurement of the three phase currents (fundamental and harmonics up to the 11th)



- Protective & control functions

27	Undervoltage
37	Undercurrent
46	Phase unbalance
46N	Neutral unbalance overcurrent with inherent unbalance compensation
49	Thermal image (for series reactor)
50/51	Fundamental frequency phase overcurrent
50/51	RMS phase overcurrent
50N/51N	Computed residual overcurrent
59	Overvoltage
BF	Breaker Failure
TD	Discharge Timer

— Measuring inputs

- Three phase current inputs and one unbalance neutral current input, with nominal currents independently selectable at 1 A or 5 A through DIP-switches.
- Three phase voltage inputs with programmable nominal voltages within range 50...130 V ($U_R=100$ V).

— Construction

According to the hardware configurations, the NC20 protection relay can be shipped in various case styles depending on the required mounting options (flush, projecting mounting, rack or with separate operator panel).

— Output relays

Six output relays are available (two changeover, three make and one break contacts); each relay may be individually programmed as normal state (normally energized, de-energized or pulse) and reset mode (manual or automatic).

A programmable timer is provided for each relay (minimum pulse width). The user may program the function of each relay according to a matrix (tripping matrix) structure.

— Binary inputs

Two binary inputs are available with programmable active state (active-ON/active-OFF) and programmable timer (active to OFF/ON or ON/OFF transitions).

Several presettable functions can be associated to each input.

— Modular design

In order to extend I/O capability, the NC20 hardware can be customized through external auxiliary modules:

- MRI - Output relays and LEDs (provided with NA80)
- MID16 - Binary inputs
- MCI - 4...20 mA converters
- MPT - Pt100 probe inputs.



— Blocking input/outputs

One output blocking circuit and one input blocking circuit are provided.

The output blocking circuits of one or several Pro_N relays, shunted together, must be connected to the input blocking circuit of the protection relay, which is installed upstream in the electric plant. The output circuit works as a simple contact, whose condition is detected by the input circuit of the upstream protection relay.

The block circuit is fed internally to the relay by the input.

For long distances, when high insulation and high EMC immunity is essential, a suitable pilot wire to fiber optic converter (BFO) is available.

— Firmware updating

The use of flash memory units allows on-site firmware updating.

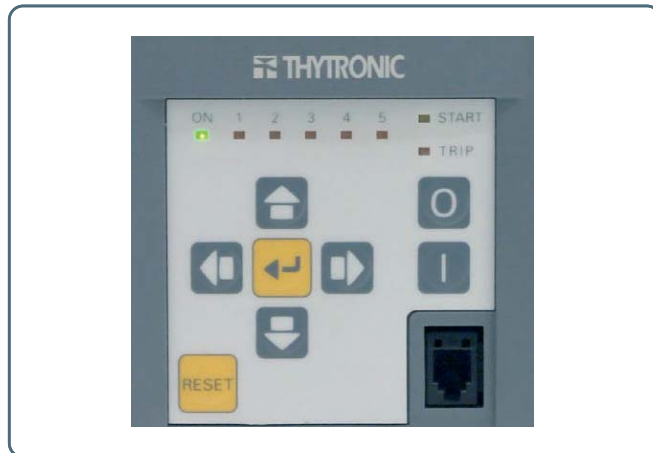
— Two set point profiles (A,B)

Two independent groups of settings are provided. Switching from profiles may be operated by means of MMI, binary input and communication.

— MMI (Man Machine Interface)

The user interface comprises a membrane keyboard, a backlight LCD alphanumeric display and eight LEDs.

The green ON LED indicates auxiliary power supply and self diagnostics, two LEDs are dedicated to the Start and Trip (yellow for Start, red for Trip) and five red LEDs are user assignable.



— Communication

Multiple communication interfaces are implemented:

- One RS232 local communication front-end interface for communication with ThySetter setup software
- Two back-end interfaces for communication with remote monitoring and control systems by:
 - RS485 port - ModBus® RTU, IEC 60870-5-103 or DNP3 protocol,
 - Ethernet port (RJ45 or optical fiber) - ModBus/TCP protocol.

— Programming and settings

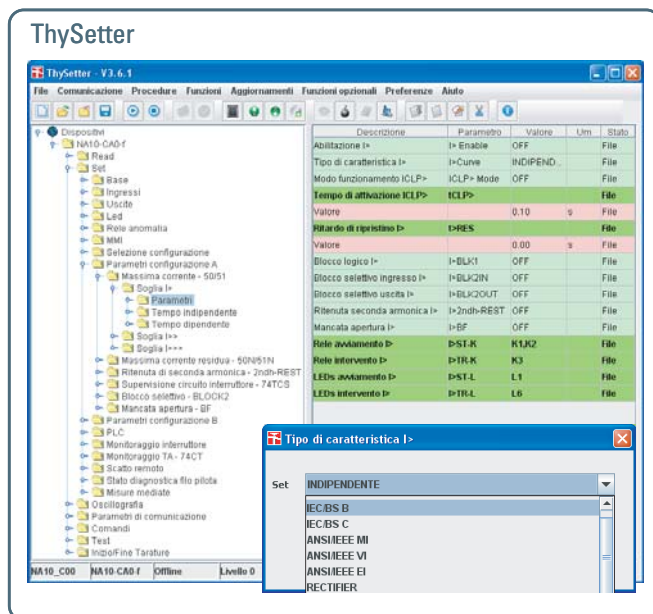
All relay programming and adjustment operations may be performed through MMI (Keyboard and display) or using a Personal Computer with the aid of the ThySetter software.

The same PC setup software is required to set, monitor and configure all Pro_N devices.

Full access to the available data is provided:

- Read status and measures
- Read/edit settings (on-line or off-line edit)

Two session level (User or Administrator) with password for sensible data access are provided.



— Self diagnostics

All hardware and software functions are repeatedly checked and any anomalies reported via display messages, communication interfaces, LEDs and output relays.

Anomalies may refer to:

- Hw faults (auxiliary power supply, output relay coil interruptions, MMI board...).
- Sw faults (boot and run time tests for data base, EEPROM memory checksum failure, data BUS,...).
- Pilot wire faults (break or short in the wire).
- Circuit breaker faults.

— Metering

NC20 provides metering values for voltages, phase and neutral currents, making them available for reading on a display or to communication interfaces.

Input signals are sampled 24 times per period and the RMS value of the fundamental component is measured using the DFT (Discrete Fourier Transform) algorithm and digital filtering.

The RMS value of phase currents are also calculated taking into account the contribution of fundamental and harmonic up to eleventh order.

On the base of the direct measurements, the minimum-peak-fixed-rolling demand, mean-minimum-maximum absolute phase currents are processed.

The measured signals can be displayed with reference to nominal values or directly expressed in amperes and volts.

— Event storage

Several useful data are stored for diagnostic purpose; the events are stored into a non volatile memory.

They are graded from the newest to the older after the "Events reading" command (ThySetter) is issued:

- Sequence of Event Recorder (SER)
The event recorder runs continuously capturing in circular mode the last three hundred events upon trigger of binary input/output.
- Sequence of Fault Recorder (SFR)
The event recorder runs continuously capturing in circular mode the last twenty events upon trigger of binary input/output and/or element pickup (start-trip).
- Trip counters

— Digital Fault Recorder (Oscillography)

Upon trigger of tripping/starting of each function or external signals, the relay records in COMTRADE format:

- Oscillography with instantaneous values for transient analysis.
- RMS values for long time periods analysis.
- Logic states (binary inputs and output relays).

Note - A license for Digital Fault Recorder function is required, the records are stored in nonvolatile memory

— Control and monitoring

Several predefined functions are implemented:

- Circuit Breaker commands and diagnostic
- Activation of two set point profiles
- CTs monitoring (74CT)
- Logic selectivity
- Cold load pickup (CLP) with block or setting change
- Trip circuit supervision (74TCS)
- Remote tripping

Moreover user defined logic must be customized in accordance with IEC 61131-3 protocol by means programmable logic controller (PLC).

Circuit Breaker commands and diagnostic

Several diagnostic, monitoring and control functions are provided:

- Health thresholds can be set; when the accumulated duty (ΣI or $\Sigma I^2 t$), the number of operations or the opening time exceeds the threshold an alarm is activated.
- Breaker failure (BF); breaker status is monitored by means 52a-52b and/or through line current measurements.
- Trip Circuit Supervision (74TCS).
- Breaker control; opening and closing commands can be carried out locally or remotely.
- Breaker inhibition; closing operations are inhibited during the time that t_D is in progress.

Logic selectivity

With the aim of providing a fast selective protection system some protective functions may be blocked (pilot wire accelerated logic). To guarantee maximum fail-safety, the relay performs a run time monitoring for pilot wire continuity and pilot wire shorting. Exactly the output blocking circuit periodically produces a pulse, having a small enough width in order to be ignored as an effective blocking signal by the input blocking circuit of the upwards protection, but suitable to prove the continuity of the pilot wire. Furthermore a permanent activation (or better, with a duration longer than a preset time) of the blocking signal is identified, as a warning for a possible short circuit in the pilot wire or in the output circuit of the downstream protection.

Cold Load Pickup (CLP)

The Cold Load Pickup feature can operate in two following modes:

- Each protective element can be blocked for a programmable time.
- Each threshold can be increased for a programmable time. It is triggered by the circuit breaker closing.



SPECIFICATIONS

GENERAL

- **Mechanical data**
Mounting: flush, projecting, rack or separated operator panel
Mass (flush mounting case) 2.0 kg
- **Insulation tests**
Reference standards EN 60255-5
High voltage test 50Hz 2 kV 60 s
Impulse voltage withstand (1.2/50 μ s) 5 kV
Insulation resistance >100 M Ω
- **Voltage dip and interruption**
Reference standards EN 61000-4-29
- **EMC tests for interference immunity**
1 MHz damped oscillatory wave EN 60255-22-1 1 kV-2.5 kV
Electrostatic discharge EN 60255-22-2 8 kV
Fast transient burst (5/50 ns) EN 60255-22-4 4 kV
Conducted radio-frequency fields EN 60255-22-6 10 V
Radiated radio-frequency fields EN 60255-4-3 10 V/m
High energy pulse EN 61000-4-5 2 kV
Magnetic field 50 Hz EN 61000-4-8 1 kA/m
Damped oscillatory wave EN 61000-4-12 2.5 kV
Ring wave EN 61000-4-12 2 kV
Conducted common mode (0...150 kHz) EN 61000-4-16 10 V
- **Emission**
Reference standards EN 61000-6-4 (ex EN 50081-2)
Conducted emission 0.15...30 MHz Class A
Radiated emission 30...1000 MHz Class A
- **Climatic tests**
Reference standards IEC 60068-x, ENEL R CLI 01, CEI 50
- **Mechanical tests**
Reference standards EN 60255-21-1, 21-2, 21-3
- **Safety requirements**
Reference standards EN 61010-1
Pollution degree 3
Reference voltage 250 V
Overvoltage III
Pulse voltage 5 kV
Reference standards EN 60529
Protection degree:
• Front side IP52
• Rear side, connection terminals IP20
- **Environmental conditions**
Ambient temperature -25...+70 °C
Storage temperature -40...+85 °C
Relative humidity 10...95 %
Atmospheric pressure 70...110 kPa
- **Certifications**
Product standard for measuring relays EN 50263
CE conformity
• EMC Directive 89/336/EEC
• Low Voltage Directive 73/23/EEC
Type tests IEC 60255-6

COMMUNICATION INTERFACES

- Local PC RS232 19200 bps
- Network:
• RS485 1200...57600 bps
• Ethernet 100BaseT 100 Mbps
Protocol ModBus® RTU/IEC 60870-5-103/DNP3, TCP/IP

INPUT CIRCUITS

- **Auxiliary power supply Uaux**
Nominal value (range) 24...48 Vac/dc, 115...230 Vac/110...220 Vdc
Operative range (each one of the above nominal values) 19...60 Vac/dc
85...265 Vac/75...300 Vdc

Power consumption:
• Maximum (energized relays, Ethernet TX) 10 W (20 VA)
• Maximum (energized relays, Ethernet FX) 15 W (25 VA)
- **Phase current inputs**
Nominal current I_n 1 A or 5 A selectable by DIP Switches
Permanent overload 25 A
Thermal overload (1s) 500 A
Rated consumption (for any phase) ≤ 0.002 VA ($I_n = 1$ A)
 ≤ 0.04 VA ($I_n = 5$ A)
- **Unbalanced neutral current input**
Nominal current I_{Nn} 1 A or 5 A selectable by DIP Switch
Permanent overload 25 A
Thermal overload (1 s) 500 A
Rated consumption ≤ 0.006 VA ($I_{En} = 1$ A)
 ≤ 0.012 VA ($I_{En} = 5$ A)
- **Voltage inputs**
Reference voltage U_R 100 V
Nominal voltage U_n 50...130 V selectable by sw
Permanent overload 1.3 U_R
1s overload 2 U_R
Rated consumption (for any phase) ≤ 0.5 VA
- **Binary inputs**
Quantity 2
Type dry inputs
Max permissible voltage 19...265 Vac/19...300 Vdc
Max consumption, energized 3 mA

- **Block input (Logic selectivity)**
Quantity 1
Type polarized wet input (powered by internal isolated supply)
Max consumption, energized 5 mA

OUTPUT CIRCUITS

- **Output relays K1...K6**
Quantity 6
• Type of contacts K1, K2 changeover (SPDT, type C)
• Type of contacts K3, K4, K5 make (SPST-NO, type A)
• Type of contacts K6 break (SPST-NC, type B)
Nominal current 8 A
Nominal voltage/max switching voltage 250 Vac/400 Vac
Breaking capacity:
• Direct current (L/R = 40 ms) 50 W
• Alternating current ($\lambda = 0,4$) 1250 VA
Make 1000 W/VA
Short duration current (0,5 s) 30 A

- **Block output (Logic selectivity)**
Quantity 1
Type optocoupler

- **LEDs**
Quantity 8
• ON/fail (green) 1
• Start (yellow) 1
• Trip (red) 1
• Allocatable (red) 5

GENERAL SETTINGS

— Rated values

Relay nominal frequency (f_n)	50, 60 Hz
Relay phase nominal current (I_n)	1 A, 5 A
Phase CTs nominal primary current (I_{np})	1 A...10 kA
Relay unbalance nominal current (I_{Nn})	1 A, 5 A
Unbalance CT nominal primary current (I_{Nnp})	1 A...10 kA
Relay nominal voltage (U_n)	50...130 V
Line VT primary nominal voltage (U_{np})	50 V...500 kV

— Compensation - 46N

Compensation current (I_c)	0.01...0.50 I_{Nn}
Compensation angle (Ph_{Ic})	0...359 °
Automatic compensation enable	ON/OFF

— Binary input timers

ON delay time (t_{IN1ON} , t_{IN2ON})	0.00...100.0 s
OFF delay time (t_{IN1OFF} , t_{IN2OFF})	0.00...100.0 s
Logic	Active-ON/Active-OFF

— Relay output timers

Minimum pulse width (t_{TR})	0.000...0.500 s
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PROTECTIVE FUNCTIONS

— Base current IB

Base current (I_B)	0.10...2.50 I_n
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— Thermal protection with RTD thermometric probes - 26

Alarm

• Alarm threshold θ_{ALx} ($x=1...8$)	0...200 °C
• Operating time $t_{\theta ALx}$ ($x=1...8$)	0...100 s

Trip

• Trip threshold θ_{Tx} ($x=1...8$)	0...200 °C
• Operating time $t_{\theta Tx}$ ($x=1...8$)	0...100 s

Note: The element becomes available when the MPT module is enabled and connected to Thybus

— Undervoltage - 27

Common configuration:

• 27 Operating logic (Logic27)	AND/OR
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U< Element

• U< Curve type (U<Curve)	DEFINITE, INVERSE ^[1]
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Definite time

• 27 First threshold definite time ($U_{<def}$)	0.05...1.10 U_n
• U<def Operating time ($t_{U<def}$)	0.03...100.0 s

Inverse time

• 27 First threshold inverse time ($U_{<inv}$)	0.05...1.10 U_n
• U<inv Operating time ($t_{U<inv}$)	0.10...100.0 s

U<< Element

Definite time

• 27 Second threshold definite time ($U_{<<def}$)	0.05...1.10 U_n
• U<<def Operating time ($t_{U<<def}$)	0.03...100.0 s

Note [1] - The mathematical formula for INVERSE curves is:

$$t = 0.75 \cdot t_{U<inv} / [1 - (U/U_{<inv})]$$

where:

t = trip time (in seconds)

$t_{U<inv}$ = operating time setting (in seconds)

U = input voltage

$U_{<inv}$ = threshold setting

— Undercurrent - 37^[1]

I< Element

• I<def Operating logic	OR ^[2]
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Definite time

• 37 First threshold definite time ($I_{<def}$)	0.05...1.00 I_n
• I<def Operating time ($t_{<def}$)	0.04...200.0 s

I<< Element

• I<<def Operating logic	AND ^[3]
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Definite time

• 37 Second threshold definite time ($I_{<<def}$)	0.05...1.00 I_n
• I<<def Operating time ($t_{<<def}$)	0.04...200.0 s

Note [1] - The 37 protection is based on RMS value measurement of three phase currents (the computed RMS value takes into account the contribution of fundamental and harmonic up to eleventh order.)

Note [2] - Starting of I<def threshold takes place when at least one phase currents is undershot.

Note [3] - Starting of I<<def threshold takes place when all three phase currents are undershot.

— Discharge time (TD)

TD discharge time (t_D)	0.1...100.0 min
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Note - When enabled it is started by the second threshold of the undercurrent protection (I<<).

— Phase unbalance - 46

I₂> Element

• I ₂ CLP> Activation time ($t_{2CLP>}$)	0.00...100.0 s
• I ₂ > Reset time delay ($t_{2>RES}$)	0.00...100.0 s

Definite time

• 46 First threshold definite time ($I_{2>def}$)	1...150 %
• I _{2>def} within CLP ($I_{2CLP>def}$)	1...150 %
• I _{2>def} Operating time ($t_{2>def}$)	0.05...60.0 s

I₂>> Element

• I ₂ CLP>> Activation time ($t_{2CLP>>}$)	0.00...100.0 s
• I ₂ >> Reset time delay ($t_{2>>RES}$)	0.00...100.0 s

Definite time

• 46 Second threshold definite time ($I_{2>>def}$)	1...150 %
• I _{2>>def} within CLP ($I_{2CLP>>def}$)	1...150 %
• I _{2>>def} Operating time ($t_{2>>def}$)	0.05...60.0 s

— Neutral unbalance current - 46N

I_{N>AL} Element

• I _{NCLP>AL} Activation time ($t_{NCLP>AL}$)	0.00...100.0 s
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Definite time

• 46N Alarm threshold definite time ($I_{N>ALdef}$)	0.01...1.00 I_{Nn}
• I _{N>ALdef} within CLP ($I_{NCLP>ALdef}$)	0.01...1.00 I_{Nn}
• I _{N>ALdef} Operating time ($t_{N>ALdef}$)	0.03...500 s

I_{N>} Element

• I _{N>} Curve type (I _{N>} Curve)	DEFINITE
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IEC/BS A, B, C, ANSI/IEEE MI, VI, EI

• I _{NCLP>} Activation time ($t_{NCLP>}$)	0.00...100.0 s
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Definite time

• 46N First threshold definite time ($I_{N>def}$)	0.01...2.00 I_{Nn}
• I _{N>def} within CLP ($I_{NCLP>def}$)	0.01...2.00 I_{Nn}
• I _{N>def} Operating time ($t_{N>def}$)	0.03...50.0 s

Inverse time

• 46N First threshold inverse time ($I_{N>inv}$)	0.01...1.00 I_{Nn}
• I _{N>inv} within CLP ($I_{NCLP>inv}$)	0.01...1.00 I_{Nn}
• I _{N>inv} Operating time ($t_{N>inv}$)	0.02...60.0 s

I_{N>>} Element

• I _{NCLP>>} Activation time ($t_{NCLP>>}$)	0.00...100.0 s
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Definite time

• 46N Second threshold definite time ($I_{N>>def}$)	0.01...2.00 I_{Nn}
• I _{N>>def} within CLP ($I_{NCLP>>def}$)	0.01...2.00 I_{Nn}
• I _{N>>def} Operating time ($t_{N>>def}$)	0.03...50.0 s

— Thermal image - 49

Common configuration:

• Initial thermal image $\Delta\theta_{IN}$ (Dth_{IN})	0.0...1.0 $\Delta\theta_B$
• Reduction factor at inrush (K_{INR})	1.0...3.0
• Thermal time constant τ (T)	1...200 min
• DthCLP Activation time (t_{DthCLP})	0.00...100.0 s

DthAL1 Element

• 49 First alarm threshold $\Delta\theta_{AL1}$ (Dth_{AL1})	0.3...1.0 $\Delta\theta_B$
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DthAL2 Element

• 49 Second alarm threshold $\Delta\theta_{AL2}$ (Dth_{AL2})	0.5...1.2 $\Delta\theta_B$
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Dth> Element

- 49 Trip threshold $\Delta\theta$ (Dth>) 1.100...1.300 $\Delta\theta_B$

Note - The 49 protection is based on maximum of the RMS value measurement of three phase currents (the computed RMS value takes into account the contribution of fundamental and harmonic up to eleventh order.)

— Phase overcurrent - 50/51 Fundamental

I>> Element

- ICLP>> Activation time ($t_{CLP>>}$) 0.00...100.0 s
- I>> Reset time delay ($t>>RES$) 0.00...100.0 s

Definite time

- 50/51 Second threshold definite time ($I>>def$) 0.100...40.0 I_n
- I>>def within CLP ($I_{CLP>>def}$) 0.100...40.0 I_n
- I>>def Operating time ($t>>def$) 0.03...10.00 s

I>>> Element

- ICLP>>> Activation time ($t_{CLP>>>}$) 0.00...100.0 s
- I>>> Reset time delay ($t>>>RES$) 0.00...100.0 s

Definite time

- 50/51 Third threshold definite time ($I>>>def$) 0.100...40.0 I_n
- I>>>def within CLP ($I_{CLP>>>def}$) 0.100...40.0 I_n
- I>>>def Operating time ($t>>>def$) 0.03...10.00 s

— Phase overcurrent - 50/51 RMS ^[1]

I>AL element

- ICLP>AL Activation time ($t_{CLP>AL}$) 0.00...100.0 s

Definite time

- 50/51 Alarm threshold definite time ($I>ALdef$) 0.100...10.00 I_n
- I>ALdef within CLP ($I_{CLP>ALdef}$) 0.100...10.00 I_n
- I>ALdef Operate time ($t>ALdef$) 0.03...200 s

I> Element

- I> Curve type (I>Curve) DEFINITE
IEC/BS A, B, C, ANSI/IEEE MI, VI, EI
CAPACITOR ^[2]

- ICLP> Activation time ($t_{CLP>}$) 0.00...100.0 s
- I> Reset time delay ($t>RES$) 0.00...100.0 s

Definite time

- 50/51 First threshold definite time ($I>def$) 0.100...10.00 I_n
- I>def within CLP ($I_{CLP>def}$) 0.100...10.00 I_n
- I>def Operating time ($t>def$) 0.03...200 s

Inverse time

- 50/51 First threshold inverse time ($I>inv$) 0.100...10.00 I_n
- I>inv within CLP ($I_{CLP>inv}$) 0.100...10.00 I_n
- I>inv Operating time ($t>inv$) 0.02...60.0 s

Note [1] - The 50/51 RMS protection is based on RMS value measurement of three phase currents (the computed RMS value takes into account the contribution of fundamental and harmonic up to eleventh order)

Note [2] - The mathematical formula for CAPACITOR curves is:

$$t = \frac{t_{inv} \cdot 50000}{[1.1 \cdot (I_{RMS}/I_{>inv})^{17-1}]} + 0.1$$

where:

- t = trip time (in seconds)
- t_{inv} = operating time setting (in seconds)
- I_{RMS} = input current
- $I_{>inv}$ = threshold setting

— Residual overcurrent - 50N/51N

I_E> Element

- I_E> Curve type (I_E>Curve) DEFINITE
IEC/BS A, B, C, ANSI/IEEE MI, VI, EI
- I_ECLP> Activation time ($t_{ECLP>}$) 0.00...100.0 s
- I_E> Reset time delay ($t_{E>RES}$) 0.00...100.0 s

Definite time

- 50N/51N First threshold definite time ($I_E>def$) 0.100...10.00 I_n
- I_E>def within CLP ($I_{ECLP>def}$) 0.100...10.00 I_n
- I_E>def Operating time ($t_{E>def}$) 0.04...200 s

Inverse time

- 50N/51N First threshold inverse time ($I_E>inv$) 0.100...10.00 I_n

- I_E>inv within CLP ($I_{ECLP>inv}$) 0.100...10.00 I_n
- I_E>inv Operating time ($t_{E>inv}$) 0.02...60.0 s

I_E>> Element

- I_ECLP>> Activation time ($t_{ECLP>>}$) 0.00...100.0 s
- I_E>> Reset time delay ($t_{E>>RES}$) 0.00...100.0 s

Definite time

- 50N/51N Second threshold definite time ($I_E>>def$) 0.100...40.0 I_n
- I_E>>def within CLP ($I_{ECLP>>def}$) 0.100...40.0 I_n
- I_E>>def Operating time ($t_{E>>def}$) 0.03...10.00 s

I_E>>> Element

- I_ECLP>>> Activation time ($t_{ECLP>>>}$) 0.00...100.0 s
- I_ECLP>>> Reset time delay ($t_{E>>>RES}$) 0.00...100.0 s

Definite time

- 50N/51N Third threshold definite time ($I_E>>>def$) 0.100...40.0 I_n
- I_ECLP>>>def within CLP ($I_{ECLP>>>def}$) 0.100...40.0 I_n
- I_ECLP>>>def Operating time ($t_{E>>>def}$) 0.03...10.00 s

Note - The residual current I_{EC} is calculated from the vector sum of the three phase currents.

— Overvoltage - 59

- 59 Operating logic (Logic59) AND/OR

U> Element

- U> Curve type (U>Curve) DEFINITE, INVERSE ^[1]

Definite time

- 59 First threshold definite time ($U>def$) 0.50...1.50 U_n
- U>def Operating time ($t_{U>def}$) 0.03...100.0 s

Inverse time

- 59 First threshold inverse time ($U>inv$) 0.50...1.50 U_n
- U>inv Operating time ($t_{U>inv}$) 0.10...100.0 s

U>> Element

Definite time

- 59 Second threshold definite time ($U>>def$) 0.50...1.50 U_n
- U>>def Operating time ($t_{U>>def}$) 0.03...100.0 s

Note [1] - The mathematical formula for INVERSE curves is:

$$t = \frac{0.5 \cdot t_{U>inv}}{[(U/U_{>inv}) - 1]}$$

where:

- t = trip time (in seconds)
- $t_{U>inv}$ = operating time setting (in seconds)
- U = input voltage
- $U_{>inv}$ = threshold

— Circuit Breaker supervision

- Number of CB trips threshold (N.Open) 0...10000
- Cumulative CB tripping currents threshold (SumI) 0...5000 I_n
- CB opening time for $\Sigma I^2 t$ computation (t_{break}) 0.05...1.00 s
- Cumulative CB tripping $\Sigma I^2 t$ threshold (SumI²t) 0...5000 (I_n)²·s
- CB Max allowed opening time ($t_{break>}$) 0.050...1.000 s

— Pilot wire diagnostic

- BLOUT1 Diagnostic pulses period (PulseBLOUT1) OFF - 0.1-1-5-10-60-120 s
- BLIN1 Diagnostic pulses window (PulseBLIN1) OFF - 0.1-1-5-10-60-120 s

— Breaker failure - BF

- BF Phase current threshold ($I_{BF>}$) 0.05...1.00 I_n
- BF Residual current threshold ($I_{EBF>}$) 0.05...1.00 I_n
- BF Time delay (t_{BF}) 0.06...10.00 s

— CT supervision - 74CT

- 74CT Threshold ($S<$) 0.10...0.95
- 74CT Overcurrent threshold (I^*) 0.10...1.00 I_n
- $S<$ Operating time ($t_{S<}$) 0.03...200 s

— Selective block - BLOCK2

Selective block IN:

- BLIN Max activation time for phase protections (t_{B-IPh}) 0.10...10.00 s
- BLIN Max activation time for ground protections (t_{B-IE}) 0.10...10.00 s

Selective block OUT:

- BLOUT Dropout time delay for phase protections (t_{F-IPh}) 0.00...1.00 s
- BLOUT Dropout time delay for phase protections (t_{F-IE}) 0.00...1.00 s
- BLOUT Dropout time delay for ground and phase protections ($t_{F-IPh/IE}$) 0.00...1.00 s

METERING & RECORDING

— Measured parameters

Direct:

- Frequency f
- RMS value of fundamental component for phase currents I_{L1}, I_{L2}, I_{L3}
- RMS value for phase currents ^[1] $I_{L1RMS}, I_{L2RMS}, I_{L3RMS}$
- RMS value of fundamental component for input voltages U_{L1}, U_{L2}, U_{L3}
- RMS value of fundamental component for unbalance neutral current I_N
- Phase displacement angle of I_N with respect to $I_{L1}(\varphi_N)$ $Ph\dot{I}_N$

Calculated:

- Thermal image $\Delta\theta$ $D\theta_{\theta}$
- RMS value of fundamental component for unbalance compensated current I_{NC}
- Phase displacement angle of I_{NC} with respect to $I_{L1}(\varphi_{NC})$ $Ph\dot{I}_{NC}$
- RMS value of fundamental component for calculated residual current I_{EC}
- Maximum RMS value between $I_{L1RMS}, I_{L2RMS}, I_{L3RMS}$ $I_{Lmax-RMS}$
- Minimum current between $I_{L1RMS}, I_{L2RMS}, I_{L3RMS}$ $I_{Lmin-RMS}$
- Average current between $I_{L1RMS}, I_{L2RMS}, I_{L3RMS}$ I_{L-RMS}
- Maximum voltage between U_{L1}, U_{L2}, U_{L3} U_{Lmax}
- Average voltage between $(U_{L1}+U_{L2}+U_{L3})/3$ U_L
- Harmonic distortion factor $THD_{-L1}, THD_{-L2}, THD_{-L3}$

Demand phase:

- Phase fixed RMS currents demand $I_{L1FIX}, I_{L2FIX}, I_{L3FIX}$
- Phase rolling RMS currents demand $I_{L1ROL}, I_{L2ROL}, I_{L3ROL}$
- Phase peak RMS currents demand $I_{L1MAX}, I_{L2MAX}, I_{L3MAX}$
- Phase minimum RMS currents demand $I_{L1MIN}, I_{L2MIN}, I_{L3MIN}$

Note [1] - The computed RMS values takes into account the contribution of harmonic up to eleventh order.

— Event recording (SER)

Number of events 300
Recording mode circular

Trigger:

- Output relays switching K1...K6...K10
- Binary inputs switching IN1, IN2...INx
- Setting changes

Data recorded:

- Event counter (resettable by ThySetter) 0...10⁹
- Event cause binary input/output relay/setting changes
- Time stamp Date and time

— Fault recording (SFR)

Number of faults 20
Recording mode circular

Trigger:

- Output relays activation (OFF-ON transition) K1...K6...K10
- External trigger (binary inputs) IN1, IN2...INx
- Element pickup (OFF-ON transition) Start/Trip

Data recorded:

- Fault counter (resettable by ThySetter) 0...10⁹
- Fundamental component currents $I_{L1r}, I_{L2r}, I_{L3r}, I_{Nr}, I_{NCr}, I_{ECr}$

- RMS phase currents $I_{L1RMS-r}, I_{L2RMS-r}, I_{L3RMS-r}$
- Fundamental frequency input voltages $U_{L1r}, U_{L2r}, U_{L3r}$
- Thermal image $D\theta_{\theta-r}$
- Phase displacement angle of I_{NC} with respect to $I_{L1}(\varphi_{NC})$ $Ph\dot{I}_{NCr}$
- Phase displacement angle of I_N with respect to $I_{L1}(\varphi_N)$ $Ph\dot{I}_{Nr}$
- Event cause start, trip, binary input
- Binary inputs state IN1, IN2...INx
- Output relays state K1...K6...K10
- Fault cause info (operating phase) L1, L2, L3
- Time stamp Date and time

— Digital Fault Recorder (Oscillography)

File format COMTRADE
Records depending on setting ^[1]
Recording mode circular
Sampling rate 24 per power frequency cycle

Trigger setup:

- Pre-trigger time 0.05...1.00 s
- Post-trigger time 0.05...60.00 s
- Trigger from inputs IN1, IN2...INx
- Trigger from outputs K1...K6...K10
- Communication ThySetter

Data recorded on sampled channels:

- Instantaneous currents $i_{L1}, i_{L2}, i_{L3}, i_N$
- Instantaneous voltages u_{L1}, u_{L2}, u_{L3}

Set analog channels (Analog 1...12):

- Frequency f
- Fundamental frequency currents $I_{L1}, I_{L2}, I_{L3}, I_N, I_{NC}, I_{EC}$
- RMS phase currents $I_{L1RMS}, I_{L2RMS}, I_{L3RMS}$
- Displacement angles $Ph\dot{I}_N, Ph\dot{I}_{NC}$
- Fundamental frequency voltages U_{L1}, U_{L2}, U_{L3}

Set digital channels (Digital 1...12):

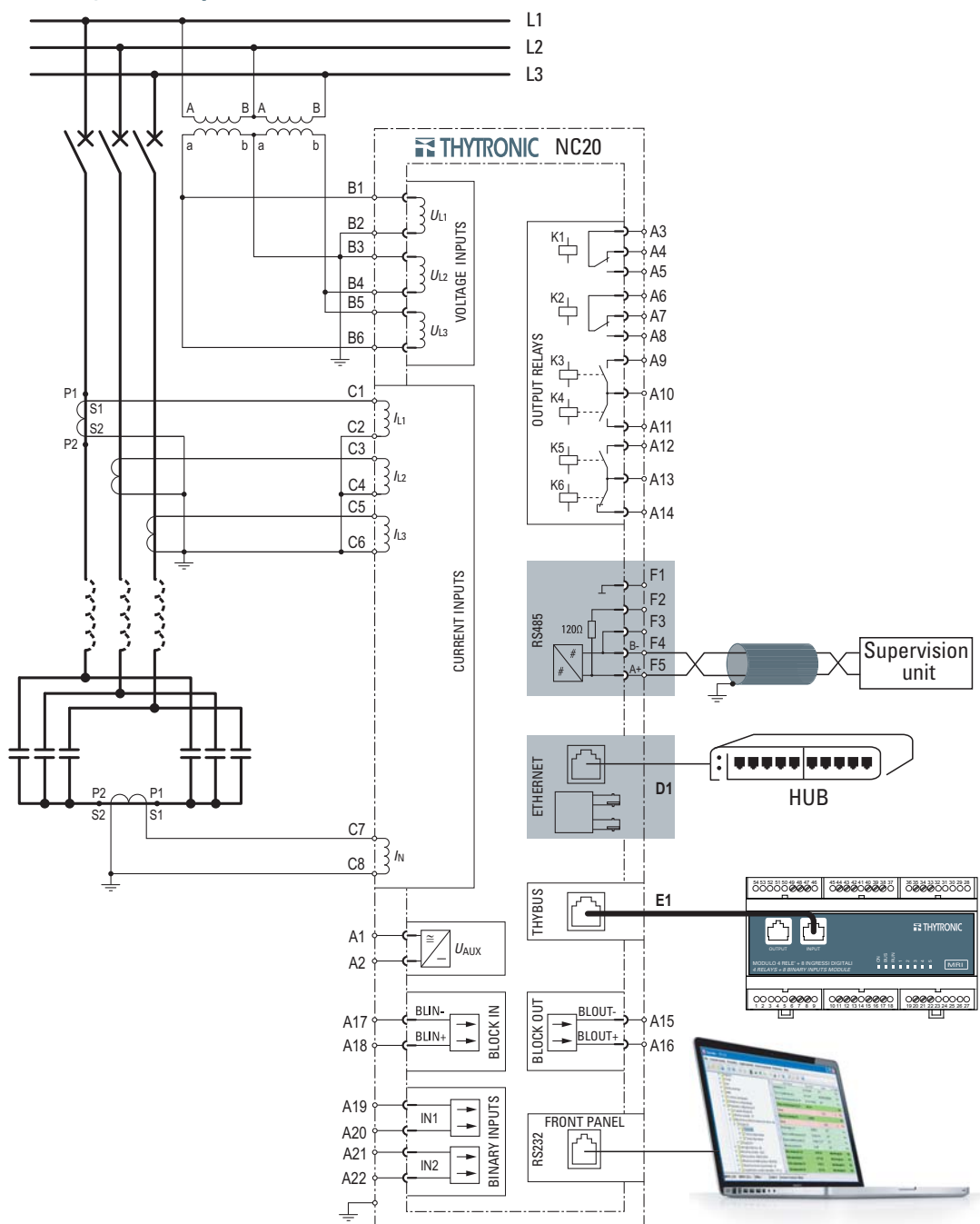
- Output relays state K1...K6...K10
- Binary inputs state IN1, IN2...INx

Note [1] - For instance, with following settings:

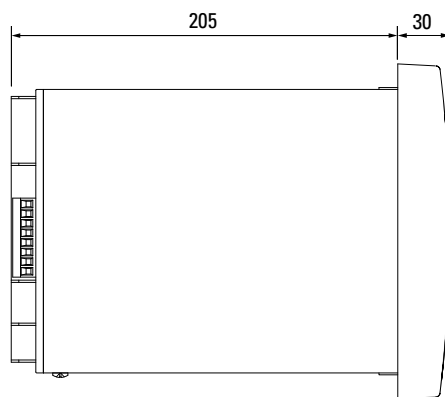
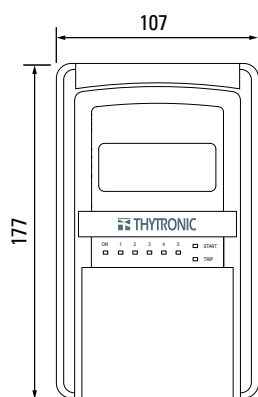
- Pre-trigger time 0.25 s
- Post-trigger time 0.25 s
- Sampled channels $i_{L1}, i_{L2}, i_{L3}, i_N, u_{L1}, u_{L2}, u_{L3}$
- Analog channels $I_{L1}, I_{L2}, I_{L3}, I_{L1RMS}, I_{L2RMS}, I_{L3RMS}, I_N$
- Digital channels K1, K2, K3, K4, K5, K6, IN1, IN2

More than three hundred records can be stored when $f = 50$ Hz

— Connection diagram example



DIMENSIONS



FLUSH MOUNTING CUTOUT

